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_APPLICATION_NO_	FILING DATE	FIRST NAMED INVENTOR		AT	TORNEY DOCKET NO.
	12/10/99	- KANO		Η '	9438-0014-2
MMC2/1003 OBLON SPIVAK MCCLELLAND MAIER & NEUSTADT P C FOURTH FLOOR 1755 JEFFERSON DAVIS HIGHWAY ARLINGTON VA 22202			一	EXAMINER BAUMEISTER, B	
				ART UNIT 2815	PAPER NUMBER

Please find below and/or attached an Office communication concerning this application or proceeding.

Commissioner of Patents and Trademarks

10/03/01

Application No.

Office Action Summary

09/461,756

Applicant(s)

Examiner

William Baumeister

Art Unit 2815

Kano

	The MAILING DATE of this communication appear	rs on the cover sheet with the correspondence address
	for Reply	
THE	ORTENED STATUTORY PERIOD FOR REPLY IS SE MAILING DATE OF THIS COMMUNICATION.	
af If the be	fter SIX (6) MONTHS from the mailing date of this commun e period for reply specified above is less than thirty (30) day e considered timely.	ys, a reply within the statutory minimum of thirty (30) days will
co - Failur - Any i	ommunication. Ire to reply within the set or extended period for reply will, I	y period will apply and will expire SIX (6) MONTHS from the mailing date of this by statute, cause the application to become ABANDONED (35 U.S.C. § 133). The mailing date of this communication, even if timely filed, may reduce any
Status		
1) 💢	Responsive to communication(s) filed on Jul 18, 2	2001
2a) 🗌	This action is FINAL . 2b) 💢 This ac	ction is non-final.
3) 🗆	Since this application is in condition for allowance closed in accordance with the practice under $\textit{Ex p}$	e except for formal matters, prosecution as to the merits is parte Quayle, 1935 C.D. 11; 453 O.G. 213.
Disposi	ition of Claims	
4) 💢	Claim(s) <u>1-31</u>	is/are pending in the application.
		is/are withdrawn from consideration.
	Claim(s)	
6) 💢	Claim(s) 1-4, 7, 8, 10, 11, 13-18, 20, and 21	is/are rejected.
7) 🗆	Claim(s)	is/are objected to.
		are subject to restriction and/or election requirement.
Applicat	tion Papers	
	The specification is objected to by the Examiner.	
	The drawing(s) filed on is/ard	
		is: a) \square approved b) \square disapproved.
12)	The oath or declaration is objected to by the Exam	niner.
	under 35 U.S.C. § 119	
	Acknowledgement is made of a claim for foreign p All b) \square Some* c) \square None of:	priority under 35 U.S.C. § 119(a)-(d).
1	1. $ ot\!$	ve been received.
2	2. Certified copies of the priority documents have	ve been received in Application No
	3. Copies of the certified copies of the priority d application from the International Bure se the attached detailed Office action for a list of the	
	Acknowledgement is made of a claim for domestic	
Attachme		
5) 💢 Not	tice of References Cited (PTO-892)	18) Interview Summery (PTO-413) Paper No(s).
	tice of Draftsperson's Patent Drawing Review (PTO-948)	19) Notice of Informal Patent Application (PTO-152)
7) 💢 Info	ormation Disclosure Statement(s) (PTO-1449) Paper No(s). 4, 5, 6	20) Other:

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DETAILED ACTION

Election/Restriction

1. Applicant's election with traverse of Species IA in Paper No. 8 is acknowledged. The traversal is on the ground(s) that the restriction has not established that an undue burden would result from examining all of the claims. This is not found persuasive because the various species possess mutually exclusive characteristics as explained in the restriction requirement, each of which requiring further consideration and search not required for the other species.

The requirement is still deemed proper and is therefore made FINAL.

Claim Objections

2. Claims 7 and 8 are objected to because of the following informalities: "bandwidth" should be changed to "bandgap." Appropriate correction is required.

Claim Rejections - 35 USC § 103

- 3. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:
 - (a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.

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- 4. Claims 1-4, 7, 8, 10, 11, 17, 18, 20 and 21 are rejected under 35 U.S.C. 103(a) as being unpatentable over Tsuji et al. '068 in view of Takagi et al., "Design of Multi-Quantum Barrier (MQB) and Experimental Verification of MQB Effect." Tsuji discloses p-i-n light-receiving or photoelectric devices wherein a series of superlattice structures are separated by well layers (carrier accumulation layers) which are composed of the same material (having the same band gap) as the wells of the superlattice (see e.g., FIGs 10-12, col. 3, line 30 and col. 8, lines 14-25). The barrier and wells layers of the superlattice regions are dimensioned so as to cause reflection above the conventional or expected conduction energy band level, creating a virtual barrier thereabove. Tsuji makes reference to earlier works of Capasso (e.g., col. 2, lines 1-) but does not expressly set forth the theory or calculations employed to set the thicknesses of the wells and barriers so as to produce this virtual barrier in the superlattice regions.
- a. Takagi teaches that a virtual barrier above the expected energy level of the barrier's conduction band may be produced by setting the thicknesses of the superlattices' barriers and wells to odd multiples of a quarter-wavelength of carriers that are to traverse the superlattice. The equations for setting these thicknesses are exactly the same as the equation set forth in claim 3 except that Takagi teaches odd-multiples instead of even multiples as set forth in the present claims (n=even integer). (Mathematical calculations showing the relationship in terms of the layers' thicknesses have previously been included in other of Applicant's applications, including US Pat #6,188,083.) It would have been obvious to one of ordinary skill in the art at the time of the invention to set the superlattice barrier and well layers of Tsuji to odd multiples of a desired

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carrier wavelength according to Takagi for the purpose of improving the carrier reflectivity above the barrier conduction at these wavelengths as taught by Tsuji and Takagi.

b. The preceding explains why motivation exists to combine the references based on producing thicknesses that are odd multiples of a quarter wavelength of an energy, but does not address the limitation of the present claims that the thicknesses be even multiples. Nonetheless, once the teachings of these references are combined in the manner and for the reasons set forth above, the resultant structure will inherently satisfy all of the limitations of the stated claims, including the limitation that the thicknesses be even multiples of a carrier wavelength. This is because the wavelength of carriers traversing the superlattices and adjacent structures is a function of the applied energy. The carrier's energy, in turn, is a function of the voltage or bias applied across the device. Thus, for a device specifically designed to reflect a given energy E (superlattice is based on odd multiples), there inherently and necessarily exists some higher energy E' such that $\lambda_{\rm E'} = 2\lambda_{\rm E}$. Restated, when the thicknesses of the barriers and wells of this superlattice are designed so as to be odd multiples of the wavelength associated with energy, E, the thicknesses will be even multiples of this other energy E'.

The Examiner notes that a recitation of the intended use of the claimed invention must result in a structural difference between the claimed invention and the prior art in order to patentably distinguish the claimed invention from the prior art. If the prior art structure is capable of performing the intended use, then it meets the claim. See, e.g., *In re Pearson*, 181 USPQ 641 (CCPA); *In re Minks*, 169 USPQ 120 (Bd Appeals); *In re Casey*, 152 USPQ 235 (CCPA 1967);

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In re Otto, 136 USPQ 458, 459 (CCPA 1963). The language of this claim, as presented, does not distinguish the present invention over the combination of Tsuji and Takagi which possesses the same structure, as claimed.

c. Regarding claims 10 and 11, Tsuji discloses that the non-superlattice well (or carrier accumulation) layer where avalanche ionization takes place is designed to be very thin (e.g., col. 3, lines 52-56) but does not specifically disclose that the thickness is equal to the wavelength of the carriers. Nonetheless, it was well known that decreasing the thickness of the avalanche photodetector will increase the carrier transit time, thereby improving the device's performance, so these well layers should be made as thin as possible. Further, the avalanche photodetector of Tsuji operates by the electrons gaining energy from falling into the well to produce an avalanche multiplication effect. Basic quantum physics principles dictates that in order for an electron to exist in a very thin quantum well the boundary conditions for the wave function must be satisfied such that the well thickness is a half wavelength of the carrier energy or a multiple thereof (e.g., particle in a box model). Restated, it would have been obvious to one of ordinary skill in the art at the time of the invention to form the well thickness to be equal to $n\lambda/2$ where n = an integer for the purpose of improving the device's operation. It would have been further obvious to specifically set the well thickness based on n = 1 (i.e. the thickness being $\lambda/2$) for the purpose of allowing the electron entering the well to reach the lowest possible energy level to further maximize the device's operation. In such a design configuration where the carrier accumulation layer is set to a thickness $d = \lambda_E/2$ for a carrier energy E, the region would

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simultaneously inherently satisfy the equation $d = \lambda_{E'}$ for the situation where a bias produces carriers having E' where $\lambda_{E'} = 2\lambda_E$, as was explained above.

Claims 13-15 are rejected under 35 U.S.C. 103(a) as being unpatentable over Tsuji/Takagi as applied to the claims above, and further in view of Motoda et al. '350. Tsuji/Takagi teaches all of the limitations of the claims as explained above except for the further inclusion of delta layers at the interface of the superlattices' barriers and wells. Motoda teaches that delta layers may be employed at the interfaces of a superlattice's barriers and wells for the purpose of more sharply varying the energy band profile at this interface. Thus, it would have been obvious to one of ordinary skill in the art at the time of the invention to employ delta layers in the superlattice regions taught by Tsuji/Takagi for the purpose of more sharply varying the energy band profile, as taught by Motoda thereby further improving the desired reflection/transmission characteristic for which the superlattice is designed.

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INFORMATION ON HOW TO CONTACT THE USPTO

6. Any inquiry concerning this communication or earlier communications from the examiner

should be directed to the examiner, B. William Baumeister, at (703) 306-9165. The examiner

can normally be reached Monday through Friday, 8:30 a.m. to 5:00 p.m. If the Examiner is not

available, the Examiner's supervisor, Mr. Eddie Lee, can be reached at (703) 308-1690. Any

inquiry of a general nature or relating to the status of this application or proceeding should be

directed to the Group receptionist whose telephone number is (703) 308-0956.

B. William Baumeister

September 30, 2001

EDDIE LEE

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